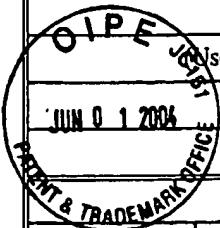


U.S. Department of Commerce, Patent and Trademark		Atty. Docket No.	Application No.
INFORMATION DISCLOSURE STATEMENT BY APPLICANT		SNDK.268US1	10/665,828
		Applicant(s)	Conf. No.
(Use several sheets if necessary)		Raul-Adrian Cernea and Yan Li	6022
JUN 01 2003		Filing Date	Group
		September 17, 2003	2818



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*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
DL	1	4,785,427	Nov. 15, 1988	Young			
	2	5,093,806	Mar. 3, 1992	Tran			
	3	5,245,571	Sep. 14, 1993	Takahashi			
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*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate

## Foreign Patent Documents

## Translation

		Document	Date	Country	Class	Subclass	Yes	No
DL	9	1134746 A2	Sep. 19, 2001	Europe				
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DL	11	International Search Report corresponding to PCT/US03/30133, International Searching Authority, European Patent Office, filed September 18, 2003, 4 pages
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Examiner Bob Jan Date Considered 12/04

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.